



Recent Insights Into Electronic Performance, Magnetism and Exchange Splittings in the Cr-substituted CaO

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The first-principles computations of density functional theory are employed to characterize the structural properties, electronic structures, and ferromagnetism induced by Cr impurities in Ca_{1-x}Cr_xO compounds at concentrations x = 0.25, 0.5, and 0.75. The dynamic stability is performed by the phonon spectra calculations. The structural parameters are computed by using Wu-Cohen generalized gradient approximation, while the electronic and magnetic properties are determined by the accurate Tran-Blaha-modified Becke–Johnson exchange potential. The crystal field, direct and indirect exchange splittings were investigated to determine the origin and stability of ferromagnetic state configuration. The Ca_{1-x}Cr_xO systems have right half-metallicities, which are verified by the spin polarization of 100% and the integer values of total magnetic moments. The Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O are half-metallic ferromagnetic with flip-gaps of 1.495, 0.888, and 0.218 eV, respectively. Therefore, the Ca_{1-x}Cr_xO materials are suitable candidates for possible applications of spin-injection in future semiconductors spintronics.

Keywords: first-principles calculations, electronic structures, ferromagnetism, exchange splittings, spintronics

INTRODUCTION

In recent years, the exploitation of new materials for technological development has become an attractive area of research for the scientific community. Spintronics is a modern field emerging from quantum electronics relating to exploration and control of the electron spin; it is currently an important research topic because the spin-based devices have interesting multifunctional characteristics such as non-volatility, data-processing speed, higher integration densities (Elilarassi and Chandrasekaran, 2017; Rai et al., 2018). In the last years, the half-metal ferromagnetic (HMF) materials have attracted considerable interest due to their wide application in spintronic devices as magnetic sensors, tunnel junctions, and spin injection sources of electrons (Özdemir and Merdan, 2019). The diluted magnetic semiconductors (DMSs) are obtained from the III–V, II–VI, or IV–VI semiconductors doped with magnetic elements, inducing changes in their structural, electronic, and magnetic properties, which are related to the concentration of magnetic impurities. These materials have received a lot of attention for scientific research because they are promising

OPEN ACCESS

Edited by:

Xiaotian Wang, Southwest University, China

Reviewed by:

Yong Li, Hangzhou Dianzi University, China Liying Wang, Tianjin University, China

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Specialty section:

This article was submitted to Theoretical and Computational Chemistry, a section of the journal Frontiers in Chemistry

> **Received:** 04 April 2020 **Accepted:** 22 May 2020 **Published:** 10 July 2020

Citation:

Doumi B, Mokaddem A, Tadjer A and Sayede A (2020) Recent Insights Into Electronic Performance, Magnetism and Exchange Splittings in the Cr-substituted CaO. Front. Chem. 8:526. doi: 10.3389/fchem.2020.00526

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candidates for innovative applications in spintronics, as an example for non-volatile memories, optical switches, and magneto-optical devices (Ohno, 1998; Dietl et al., 2000; Wolf et al., 2001; Zuti et al., 2004; Sato et al., 2010; Kumar et al., 2014).

Alkaline earth chalcogenides are important materials with a wide technological application ranging from catalysis to microelectronics as well as in the area of electro- and photoluminescent devices (Hakamata et al., 2005; Speziale et al., 2006; Murtaza et al., 2014). Among these compounds, the CaX (X = O, S, Se) has a closed-shell ionic environment, crystallizing in the rock-salt NaCl-type (B1) structure at ambient conditions (Doll et al., 1996; Mishra et al., 2012). Under high pressure, they undergo a first-order structural phase transition from the NaCltype (B1) to the CsCl-type (B2) crystal structure (Luo et al., 1994; Doll et al., 1996; Dadsetani and Doosti, 2009; Mishra et al., 2012). The CaO calcium oxide can be a potential candidate as a DMS material according to several theoretical studies (Kenmochi et al., 2004; Kemmochi et al., 2005; An Dinh et al., 2006). Kenmochi et al. (2004) have studied a new class of DMSs based on CaO without transition metals, where the substituted CaO by C and N at the oxygen sites shows room-temperature ferromagnetism with half-metallic property. The ferromagnetism in C-doped CaO is explained by the exchange coupling constants, where it is induced by the strong hybridization between 2p states of carbon and 2p states of oxygen (An Dinh et al., 2006). Further, Kemmochi et al. (2005) have found that the stability of ferromagnetic state in the C-doped CaO is originated from the Zener's double-exchange mechanism.

In this study, we have investigated the structural parameters, electronic performance, magnetism, and exchange splittings of Ca_{1-x}Cr_xO materials at various concentrations x = 0, 0.25, 0.5, and 0.75. The calculations are performed by the use of first-principle approaches of density functional theory (DFT) (Hohenberg and Kohn, 1964; Kohn and Sham, 1965) as implemented in the WIEN2k package (Blaha et al., 2001). The phonon spectra are used to verify the dynamic stability of Ca_{1-x}Cr_xO materials. The exchange and correlation potential is evaluated by the generalized gradient approximation of Wu and Cohen (GGA-WC) (Wu and Cohen, 2006), and the Tran–Blaha-modified Becke–Johnson potential (TB-mBJ) (Tran and Blaha, 2009).

COMPUTATIONAL METHODS

The calculations of structural, electronic, and magnetic properties of $Ca_{1-x}Cr_xO$ are carried out using the WIEN2k code (Blaha et al., 2001) based on the first-principle computations of DFT and the full-potential linearized augmented planewave (FP-LAPW) method (Singh and Nordstrom, 2006). We have computed the structural parameters using GGA-WC approximation (Wu and Cohen, 2006), while the electronic and magnetic properties are determined by employing the TB-mBJ exchange potential (Becke and Johnson, 2006; Tran and Blaha, 2009). The phonon frequencies are determined by the phonopy code (Togo and Tanaka, 2015) based on the density functional perturbation theory (Giannozzi et al., 1991; Gonze and Lee,

1997). The phonon spectra are calculated using the WIEN2k and the phonopy packages to verify the dynamic stability of $Ca_{1-x}Cr_xO$ doping compounds.

The averages of Muffin-tin spheres radii are selected for Ca, Cr, and O atoms in condition that Muffin-tin spheres do not overlap. The cutoff of -6 Ry is utilized to separate between the valence and core states. The basic functions and the potentials are extended in combination of spherical harmonics around the atomic sites, that is to say, the atomic spheres with a cutoff $l_{\text{max}} = 10$, and in the interstitial region are extended into plane waves with a cutoff $R_{\rm MT}k_{\rm max} = 8$ (where $R_{\rm MT}$ is the average radius of the Muffin-tin spheres). We have expanded the charge density in Fourier up to $G_{max} = 14$ $(a.u.)^{-1}$, where G_{max} represents the largest vector in the Fourier expansion. The calculations were performed for structures of eight (8) atoms of $Ca_{1-x}Cr_xO$ at concentrations x = 0, 0.25,0.5, and 0.75 such as CaO, Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O supercells. The integration of the Brillouin zone was carried out by the Monkhorst-Pack mesh (Monkhorst and Pack, 1976) using the special k-points of (10 \times 10 \times 10) for CaO and $(5 \times 5 \times 5)$ for Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O compounds. The self-consistent is achieved when the total energy convergence condition was set to be 10^{-1} mRv.

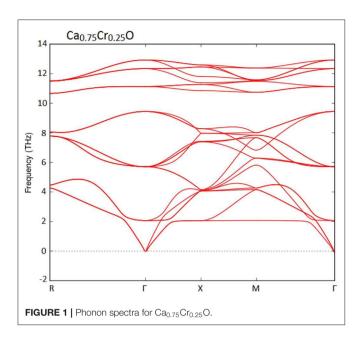
RESULTS AND DISCUSSION

Structural Properties Crystal Structures

The calcium oxide CaO is known as a wide-band gap II-VI semiconductor, crystallizing in rock-salt NaCl (B1) structure at ambient conditions (Doll et al., 1996; Mishra et al., 2012). The primitive unit cell of CaO contains two atoms such as the calcium (Ca) and the oxygen (O), which belong, respectively, to the main groups II and VI of the periodic table. Our study is based on the conventional NaCl structure of eight atoms of CaO such as Ca₄O₄, where the Ca is located at (0, 0, 0) position and the O atom at (0.5, 0.5, 0.5) with space group of $Fm\bar{3}m$ No. 225. The Ca₃CrO₄, Ca₂Cr₂O₄, and CaCr₃O₄ supercells are created by substituting one, two, and three Cr impurities at Ca sites, respectively. Consequently, we have obtained three supercells such as $Ca_{0.75}Cr_{0.25}O$ at concentration x = 0.25, $Ca_{0.5}Cr_{0.5}O$ at x =0.5 and Ca_{0.25}Cr_{0.75}O at x = 0.75. The Ca_{0.75}Cr_{0.25}O and $Ca_{0.25}Cr_{0.75}O$ have cubic lattices with space group of $Pm\bar{3}m$ No 221, while the Ca_{0.5}Cr_{0.5}O supercell has a tetragonal lattice with space group of P4/mmm No. 123. We have noticed that all symmetry operations have been considered in the initialization of structures of Ca1-xCrxO supercells for computations of different properties.

Structural Stability

The structural stability of the $Ca_{1-x}Cr_xO$ compounds in the ferromagnetic rock-salt NaCl (B1) structure is verified by computing the formation energies. The formation energies (E_{form}) of the $Ca_{4-y}Cr_yO_4$ materials are determined using the following expression (Bai et al., 2011; Doumi et al., 2015a):



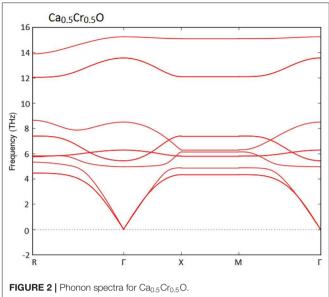
$$E_{\text{form}} = E_{\text{total}}(\text{Ca}_{4-y}\text{Cr}_{y}\text{O}_{4}) - \left(\frac{(4-y) E(\text{Ca})}{8}\right) - \left(\frac{y E(\text{Cr})}{8}\right) - \left(\frac{4 E(\text{O})}{8}\right)$$
(1)

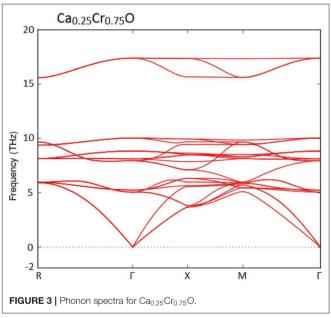
where $E_{\text{total}}(\text{Ca}_{4-y}\text{Cr}_{y}\text{O}_{4})$ corresponds to the minimum total energy of $\text{Ca}_{4-y}\text{Cr}_{y}\text{O}_{4}$ per atom, and E(Ca), E(Cr), and E(O) refer to the minimum total energies per atom of bulks Ca, Cr, and O, respectively. The y = 1, 2, and 3 are the number of substituted Cr impurities in $\text{Ca}_{4-y}\text{Cr}_{y}\text{O}_{4}$ supercells. We have found that the formation energies are -5.99, -6.37, and -6.76 eV, respectively, for $\text{Ca}_{0.75}\text{Cr}_{0.25}\text{O}$, $\text{Ca}_{0.5}\text{Cr}_{0.5}\text{O}$, and $\text{Ca}_{0.25}\text{Cr}_{0.75}\text{O}$. Therefore, the negative values of formation energies suggest that these compounds are thermodynamically stable in the ferromagnetic rock-salt structure.

Furthermore, we have used the phonon spectra to demonstrate the dynamic stability of the $Ca_{1-x}Cr_xO$ doping compounds. The diagrams of phonon frequencies at high symmetry points in the Brillouin zone of $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, and $Ca_{0.25}Cr_{0.75}O$ are shown by **Figures 1–3**, respectively. These figures depicted that all branches of phonons have positive frequencies, and there are no negative frequencies (Deng et al., 2019), confirming the dynamic stability of $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, and $Ca_{0.25}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, and $Ca_{0.25}Cr_{0.75}O$ compounds.

Equilibrium Structural Parameters

The variations of total energies as a function of volumes of $Ca_{1-x}Cr_xO$ compounds are fitted by Murnaghan (1944) equation of state to determine the equilibrium structural parameters. **Table 1** summarizes the lattice constants, the bulk modules, and their first derivatives with other experimental data (Mammone et al., 1981; Kaneko et al., 1982; Richet et al., 1988) and theoretical values (Tran et al., 2007; Wu et al., 2014; Cinthia





et al., 2015; Fan et al., 2015; Nejatipour and Dadsetani, 2015; Santana et al., 2016; Yang et al., 2016; Salam, 2018) computed by the generalized gradient approximation of Perdew–Burke– Ernzerhof (GGA-PBE) (Perdew et al., 1996), revised GGA of Perdew–Burke–Ernzerhof (GGA-PBEsol) (Perdew et al., 2008) and the local density approximation (LDA) (Perdew and Zunger, 1981; Perdew and Wang, 1992).

The results of lattice constants and bulk modulus of CaO are closed to theoretical values of Tran et al. (2007) and Fan et al. (2015) calculated with GGA-WC potential (Wu and Cohen, 2006). We see that there is a good agreement between our calculations and experimental results (Mammone et al., 1981; Kaneko et al., 1982; Richet et al., 1988) and theoretical value

Material	a (Å)	B (GPa)	B'	Method	References
This work				Generalized gradient approximation of Wu and Cohen (GGA-WC)	
CaO	4.772	113.15	4.44		
Ca _{0.75} Cr _{0.25} O	4.660	126.40	4.63		
Ca _{0.5} Cr _{0.5} O	4.549	128.91	3.63		
Ca _{0.25} Cr _{0.75} O	4.415	133.23	3.75		
Other calculations					
CaO	4.812			Experimental	Kaneko et al., 1982
		111	4.2	Experimental	Richet et al., 1988
	4.8105	115	4.1	Experimental	Mammone et al., 1981
	4.777	116		GGA-WC	Tran et al., 2007
	4.77			GGA-WC	Fan et al., 2015
	4.841	105		Generalized gradient approximation of Perdew–Burke–Ernzerhof (GGA-PBE)	Tran et al., 2007
	4.81			GGA-PBE	Fan et al., 2015
	4.857			GGA-PBE	Wu et al., 2014
	4.843	107	4.2	GGA-PBE	Cinthia et al., 2015
	4.84			GGA-PBE	Nejatipour and Dadsetani, 201
	4.834			GGA-PBE	Yang et al., 2016
	4.836	102.3	4.17	GGA-PBE	Salam, 2018
	4.77			Revised GGA of Perdew–Burke–Ernzerhof (GGA-PBEsol)	Fan et al., 2015
	4.719	129		Local density approximation (LDA)	Tran et al., 2007
	4.71			LDA	Fan et al., 2015
	4.734	119.54	4.23	LDA	Santana et al., 2016

TABLE 1 Computed structural parameters such as lattice constants (a), bulk modules (*B*), and their pressure derivatives (*B'*) for Ca_{1-x}Cr_xO materials at concentrations x = 0, 0.25, 0.5, and 0.75 with other experimental and theoretical data.

found by GGA-PBE sol (Perdew et al., 2008). On the other hand, the obtained values of these parameters with GGA-WC (Wu and Cohen, 2006) are better than the calculations of Tran et al. (2007), Wu et al. (2014) Cinthia et al. (2015), Nejatipour and Dadsetani (2015), Yang et al. (2016), Salam (2018), Tran et al. (2007), Fan et al. (2015), and Santana et al. (2016) found, respectively, by GGA-PBE (Perdew et al., 1996) and LDA approximation (Perdew and Zunger, 1981; Perdew and Wang, 1992). The performance of GGA-WC approximation for predicting structural parameters is due to the fourth-order gradient expansion of exchangecorrelation functional (Doumi et al., 2015b; Sajjad et al., 2015). For the Ca1-xCrxO doping compounds, the ionic radius of Cr is lower than that of Ca atom, leading to decrease in the lattice constant with increasing Cr concentration. Consequently, the bulk modulus of Ca_{1-x}Cr_xO increases with increasing concentration of Cr. The $Ca_{1-x}Cr_xO$ doping compound becomes harder as the concentration of Cr increases.

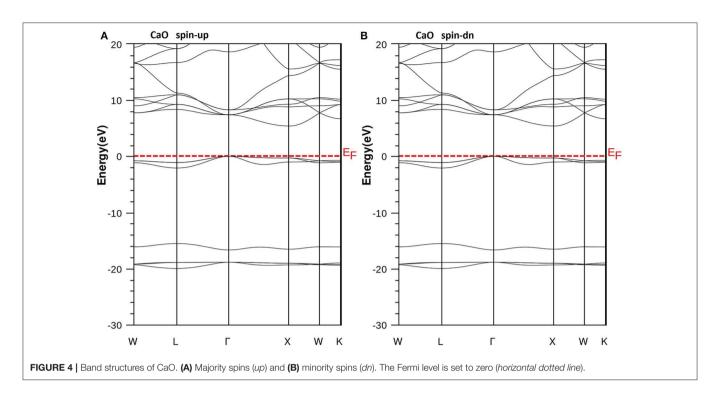
Electronic Properties

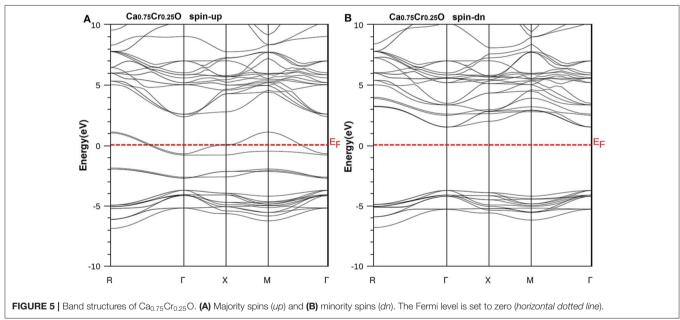
Band Structures and Half-Metallicity

We have used the predicted structural parameters to characterize the electronic structures and the half-metallicity in Ca_{1-x}Cr_xO compounds. The TB-mBJ potential is used to determine the electronic structures and accurate band gaps of Ca_{1-x}Cr_xO compounds at concentration x = 0, 0.25, 0.5, and 0.75. The band structures of CaO, Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O are shown, respectively, by the Figures 4-7.

According to Figure 4, the CaO is a semiconductor because both majority and minority spins revealed the analogous band structures with indirect gaps. The CaO has an indirect gap($E^{\Gamma X}$) between the valence bands maximum and conduction bands minimum situated, respectively, at Γ and X high symmetry points. Figures 5-7 demonstrate that the Ca1-xCrxO for all concentrations are metallic and semiconductors, respectively, for majority- and minority-spin bands. Consequently, the Ca_{1-x}Cr_xO doping materials are half-metallic ferromagnets. The metallic character is due to localized partially filled 3d-Cr states of majority spins around Fermi level $(E_{\rm F})$, which interact with carriers of valence states of host semiconductor. For minority spins, the Ca_{1-x}Cr_xO doping systems keep a semiconductor behavior as CaO compound because the 3d-Cr empty minorityspin states arise in the bottom of conduction band minimum at Γ high symmetry point far than $E_{\rm F}$. Thus, the gap nature shifted from indirect band gap for CaO to direct gap for Ca1-xCrxO doping systems.

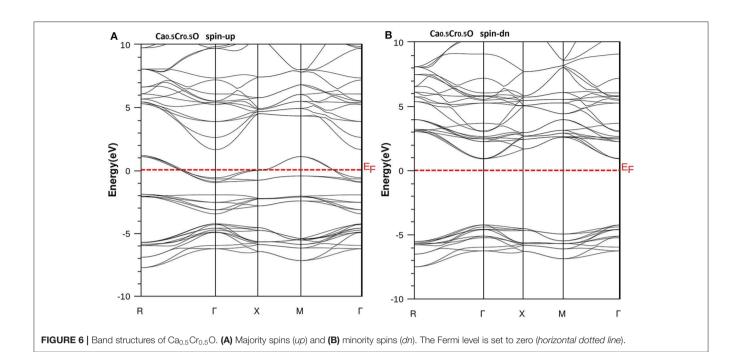
The minority spins of $Ca_{1-x}Cr_xO$ systems are characterized by direct wide-band gaps called half-metallic ferromagnetic (HMF) gaps located at the Γ high symmetry point. The minimal energies that separate the Fermi level (zero eV), and the conduction band minimums determine the half-metallic (HM) gaps. **Table 2** shows the computed band gaps such as the direct HMF gaps

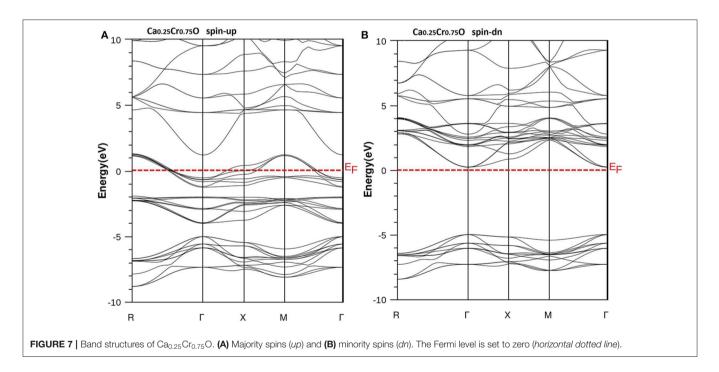




(E_{HMF}) and HM gaps (E_{HM}) of Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O, and the indirect gap ($E^{\Gamma X}$) of CaO with other theoretical (Fan et al., 2015; Nejatipour and Dadsetani, 2015; Yang et al., 2016; Tran and Blaha, 2017; Salam, 2018) and experimental data (Whited et al., 1973). The result of wide-indirect gap of 5.392 eV of CaO is in good agreement with recent calculated value of 5.35 eV of Tran and Blaha (2017) study using the same TB-mBJ potential (Becke and Johnson, 2006; Tran and Blaha, 2009), and it is better than the values ranging from

3.437 to 3.67 eV of Fan et al. (2015), Nejatipour and Dadsetani (2015), Yang et al. (2016), Tran and Blaha (2017), Salam (2018) found by the LDA (Perdew and Zunger, 1981; Perdew and Wang, 1992), GGA-WC (Wu and Cohen, 2006), GGA-PBE (Perdew et al., 1996), and GGA-PBEsol exchange potentials (Perdew et al., 2008). The TB-mBJ provides accurate gap for CaO because he is known for its performance in the calculation of electronic structures of insulators and semiconductors with respect to LDA and all forms of GGA approximations (Bhattacharjee and





Chattopadhyaya, 2017a,b; Chattopadhyaya and Bhattacharjee, 2017; Berriah et al., 2018).

Moreover, the half-metallic gap or flip-gap is an interesting performance for exploring the spin-injection for a half-metallic material in spintronics. The Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O compounds have the HM gaps of 1.495, 0.888, and 0.218 eV, respectively, situated between the conduction bands minimum (CBM) and $E_{\rm F}$. The CBM moves toward $E_{\rm F}$ due to widening of 3d-Cr empty states at the bottom of conduction band, and hence, the HM gap decreases from

 $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, to $Ca_{0.25}Cr_{0.75}O$. The HM gap behavior is maintained for different concentrations, meaning that the $Ca_{1-x}Cr_xO$ doping systems are right half-metallic materials.

Densities of States and Spin Polarization

In order to understand the origin of half-metallic feature induced by the substituting effect of Cr, we have plotted the total and partial densities of states (DOS) of Cr, Ca, and O atoms of $Ca_{1-x}Cr_xO$ compounds. **Figures 8–10** show, respectively, the DOS of $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, and $Ca_{0.25}Cr_{0.75}O$. We **TABLE 2** Computed band gaps such as indirect band gap ($E^{\Gamma x}$) for CaO, half-metallic ferromagnetic (HMF) gaps (E_{HMF}), and half-metallic (HM) gaps (E_{HM}) of minority-spin bands for Ca_{1-x}Cr_xO at concentrations x = 0.25, 0.5, and 0.75 with other theoretical and experimental data.

Material	Е _{НМF} (eV)	<i>Е</i> нм (eV)	E ^{rx} (eV)	Method	
This work					
CaO			5.392	Tran–Blaha-modified Becke–Johnson potential (TB-mBJ)	
Ca _{0.75} Cr _{0.25} C	5.242	1.495		TB-mBJ	
Ca _{0.5} Cr _{0.5} O	5.142	0.888		TB-mBJ	
Ca _{0.25} Cr _{0.75} C	5.195	0.218		TB-mBJ	
Other calcul	ations				
CaO			3.53	GGA-WC	Fan et al., 2015
			3.647	GGA-PBE	Fan et al., 2015
			3.669	GGA-PBE	Nejatipour and Dadsetani, 2015
			3.65	GGA-PBE	Yang et al., 2016
			3.658	GGA-PBE	Salam, 2018
			3.67	GGA-PBE	Tran and Blaha, 2017
			3.518	GGA-PBEsol	Fan et al., 2015
			3.437	LDA	Fan et al., 2015
			3.49	LDA	Tran and Blaha, 2017
			5.35	TB-mBJ	Tran and Blaha, 2017
			7.00	Experimental	Whited et al., 1973

clearly see that all compounds are metallic for majority spin and semiconductors for minority spin, where their bonding, non-bonding, and anti-bonding states are distinguished from each other by the contributions of the DOS formed by different orbitals of each Ca, O, and Cr atoms.

The partial DOS of Figures 8-10B revealed that the 3d-Cr states are splitted into the low-lying t_{2g} and high-lying e_{g} states owing to the effect of octahedral crystal field created by neighboring oxygen (O) ions. For both minority and majority spins, the bonding states are mainly contributed by the p-O states and by the small p-Ca and 3d-Cr states in the ranges of -6.5to -4, -7.5 to -4.5, and -8.25 to -5.25 eV, respectively, for Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O. For the majority spins of Ca_{1-x}Cr_xO, the non-bonding states are principally dominated by the t_{2g} -(3d-Cr) fully filled levels that hybridize largely with p-O orbitals, while the anti-bonding states are mostly contributed by the hybridization of the e_g -(3d-Cr) levels and p-O states around $E_{\rm F}$. However, the upper part of valence bands of majority spins is originated from both t_{2g} -(3d-Cr) non-bonding states and e_g -(3d-Cr) anti-bonding states, which extend strongly in the gap owing to broadening of 3d-Cr levels around $E_{\rm F}$.

Furthermore, the upper part of valence bands of minority spins are formed by the bonding states originated from the p-O orbitals, which are centered at -5.25, -6, and -6.75 eV for Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O, respectively. The bottom of conduction band is generated predominantly by the 3d-Cr empty anti-bonding states, which move to lower

energies toward Fermi level from $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, to $Ca_{0.25}Cr_{0.75}O$ with increasing Cr concentration. Therefore, the distinguish half-metallic ferromagnetic and half-metallic gaps are created around E_F in minority spins for $Ca_{0.75}Cr_{0.25}O$, $Ca_{0.5}Cr_{0.5}O$, and $Ca_{0.25}Cr_{0.75}O$ materials.

The spin-polarized material is known by its spin polarization of electronic structures, which is an important factor for characterizing a half-metal. The polarization (*P*) of half-metal compound results from the different contributions of numbers of DOS around E_F . It is determined from the following expression (Soulen et al., 1998; Wang et al., 2017):

$$P = \frac{\left|N \uparrow (E_F) - N \downarrow (E_F)\right|}{\left|N \uparrow (E_F) + N \downarrow (E_F)\right|} \tag{2}$$

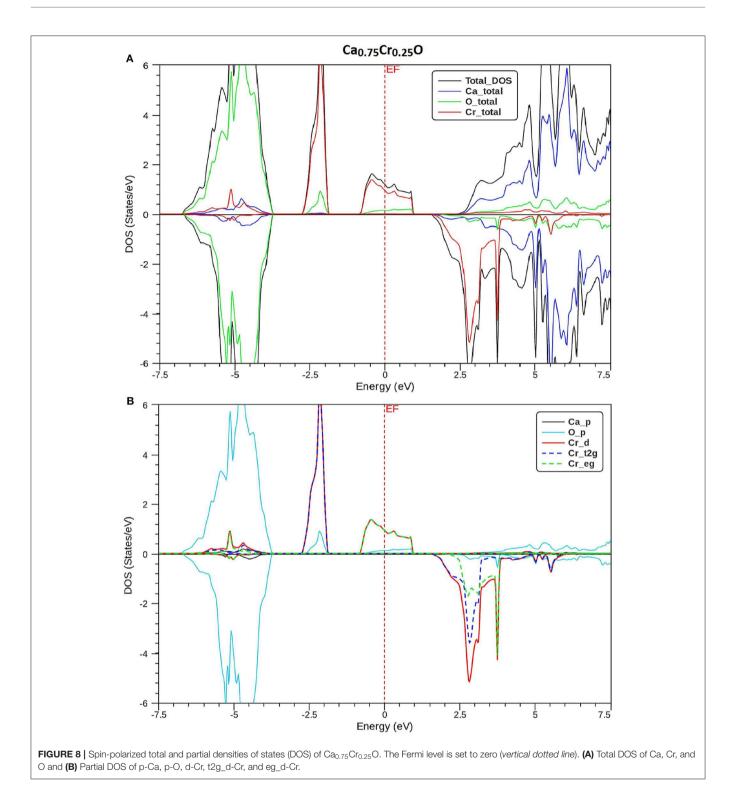
where $N \uparrow (E_F)$ and $N \downarrow (E_F)$ indicate, respectively, the DOS of majority and minority spins at E_F . From **Figures 8–10A**, the density of states $N \downarrow (E_F)$ equals zero because the DOS do not cross E_F , leading to a spin polarization of 100%. Therefore, the Ca_{1-x}Cr_xO compounds appear to be suitable candidates for possible spin-injection in spintronics applications.

Magnetic Properties Magnetic Moments

The spin-polarized electronic structures show an asymmetric character, indicating that the Ca_{1-x}Cr_xO compounds are magnetic in nature. The magnetism is induced by the magnetic spins arising from the localized 3d-Cr majority-spin states around $E_{\rm F}$. The Cr impurity contributes two electrons to host carriers of valence bands, resulting in Cr⁺² ion. Thus, the 3d-Cr states become partially filled with four electrons. Therefore, the magnetism is originated from the four itinerant electrons of Cr⁺² ions in Ca_{1-x}Cr_xO doping materials.

From the DOS of majority spins, one can see that the nonbonding states enclose three low-lying t_{2g} levels, which are completely occupied by three electrons. In contrast, the two highlying e_g states have an anti-bonding nature, which are partially occupied by one electron because they are crossed by Fermi level in the middle. According to the Hund's rule, the 3d-Cr states generate a total magnetic moment of 4 μ_B per Cr ion. Consequently, the Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O compounds have total magnetic moments of 4, 8, and 12 μ_B , respectively, for one, two, and three Cr doping impurities.

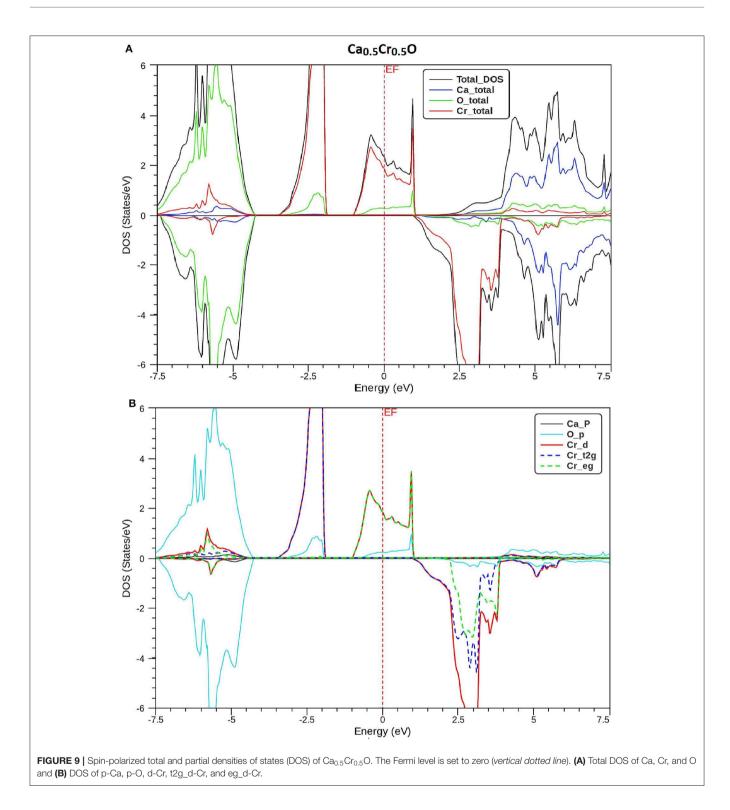
The calculated total and partial magnetic moments of Ca, Cr, and O atoms and in the interstitial sites for Ca_{0.75}Cr_{0.25}O, Ca_{0.5}Cr_{0.5}O, and Ca_{0.25}Cr_{0.75}O are given in **Table 3**. The total magnetic moment per Cr atom is an integer number of 4 μ _B. It is a typical feature of half-metallic materials (Wang et al., 2017; Zhang et al., 2017). All compounds have negative partial magnetic moments for O atoms, revealing that carriers of host valence bands enclosing p-O states interact anti-ferromagnetically with 3d-Cr states. Besides, the positive partial magnetic moments of Cr and Ca atoms describe the ferromagnetic interaction between Cr and Ca magnetic spins.



Exchange Splitting Mechanisms

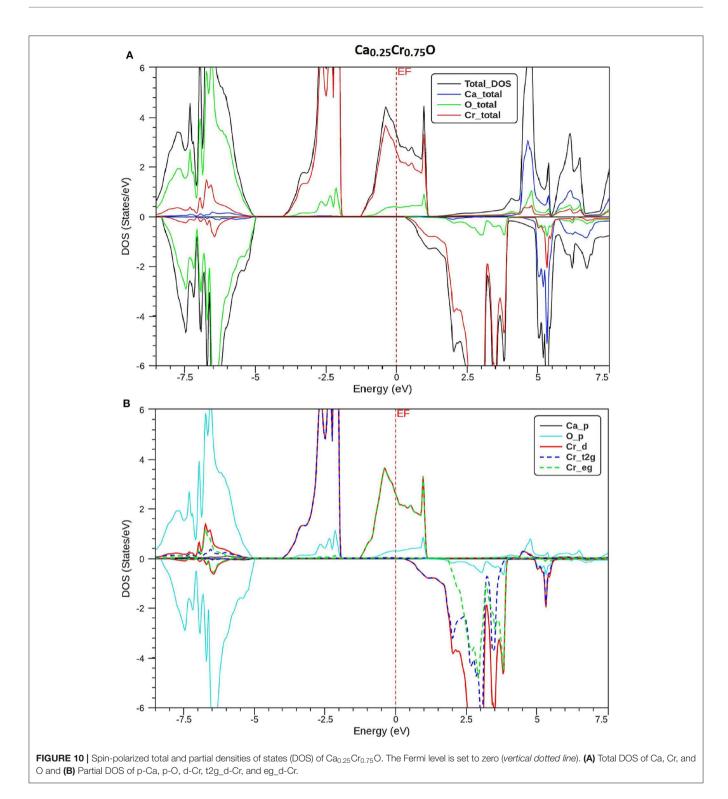
The ferromagnetism is created from the localized electrons of t_{2g} and e_{2g} of 3d-Cr states mediated by holes, where the empty holes of e_g states occur at the top of valence band and generate an acceptor hole type carrier hybridizing with carriers of host valence band (Doumi et al., 2013). The degenerate 3d-Cr into

 $t_{\rm 2g}$ and $e_{\rm 2g}$ is due to crystal field generated from the electrostatic environment of surrounding oxygen (O) ions, where the 3d-Cr majority-spin levels contain four unpaired electrons (Noor et al., 2018). According to the Hund's rule, this kind of process mediates magnetism in Ca_{1-x}Cr_xO materials (Yaqoob et al., 2019). It is understood that both exchange splitting of 3d-Cr states and



crystal field take part in the contribution of ferromagnetism in ${\rm Ca}_{1\text{-}x}{\rm Cr}_x{\rm O}$ doping materials.

The magnitude of crystal field energy (ΔE_{CF}) is defined as a difference between E_{eg} and E_{t2g} energies of e_g and t_{2g} states ($\Delta E_{CF} = E_{eg} - E_{t2g}$). The direct exchange splitting energy $\Delta_x(d) = d \downarrow -d \uparrow$ is determined from the separation between the empty d-Cr $(d \downarrow)$ minority-spin and occupied d-Cr $(d \uparrow)$ majority-spin peaks. Another factor is used to determine the magnitude of ferromagnetism such as the indirect $\Delta_x(pd) = E_{\nu}^{\uparrow} - E_{\nu}^{\uparrow}$ exchange splitting resulted from the energy difference



between E_{ν}^{\downarrow} and E_{ν}^{\uparrow} valence band maximums of minority- and majority-spin channels, respectively.

The values of ΔE_{CF} , $\Delta_x(d)$, and $\Delta_x(pd)$ exchange splitting are shown in **Table 4**. The obtained values of (ΔE_{CF} and $\Delta_x(d)$) are (1.71 and 4.98 eV), (2.97 and 4.90 eV), and (1.74 and 5.17 eV), revealing that the direct exchange splittings are more dominated compared to the crystal field splittings. Therefore, the ferromagnetism state is mainly favored by the contribution of direct exchange splitting mechanism than that of crystal field (Amin et al., 2018). Besides, the partial magnetic moment of Cr increases from 3.652 μ_B for Ca_{0.75}Cr_{0.25}O, 7.203 μ_B for Ca_{0.5}Cr_{0.5}O, to 10.541 μ_B for Ca_{0.25}Cr_{0.75}O with decreasing

TABLE 3 Computed total and partial magnetic moments of the relevant Cr, Ca, and O atoms and in the interstitial sites (in Bohr magneton μ_B) for Ca_{1-x}Cr_xO at concentrations x = 0.25, 0.5, and 0.75.

Material	Total	Cr	Ca	ο	Interstitial
Ca _{0.75} Cr _{0.25} O	4	3.652	0.009	-0.075	0.414
Ca _{0.5} Cr _{0.5} O	8	7.203	0.011	-0.049	0.835
Ca _{0.25} Cr _{0.75} O	12	10.541	0.009	-0.059	1.391

TABLE 4 | Computed energies of crystal field ΔE_{CF} , direct $\Delta_x(d)$, and indirect $\Delta_x(pd)$ exchange splittings for Ca_{1-x}Cr_xO at concentrations x = 0.25, 0.5, and 0.75.

Material	$\Delta E_{\rm CF}$ (eV)	Δ_x (d) (eV)	Δ_x (pd) (eV)	
Ca _{0.75} Cr _{0.25} O	1.71	4.98	-3.75	
Ca _{0.5} Cr _{0.5} O	2.97	4.90	-4.25	
Ca _{0.25} Cr _{0.75} O	1.74	5.17	-4.97	

 $\Delta_x(pd)$, meaning that magnetic moment of Cr is directly related to the indirect exchange splitting. On the other hand, the attraction nature of spin-polarized electrons is measured from the indirect exchange splitting (Verma et al., 2011; Mahmood et al., 2016, 2018). The indirect exchange splittings $\Delta_x(pd)$ have negative values because the valence band maximums of minority-spins are situated at lower energies with respect to the valence band maximums of majority-spins. This means that the minority-spins have more attractive (negative) potential than that of majority-spins, leading to perfectly localized magnetic states. Consequently, the ferromagnetism is preferred in the Ca1-xCrxO compounds. In the DMS based on III-V and II-VI semiconductors doped with transition metals, when the d states of magnetic dopants are partially occupied (Sato and Katayama-Yoshida, 2002; Sato et al., 2003a,b), the stability of ferromagnetism is described by the double-exchange mechanism (Akai, 1998). According to this rule, the anti-bonding states of partially filled 3d-Cr atoms associated with double-exchange mechanism stabilize the ferromagnetic state configuration in $Ca_{1-x}Cr_xO$.

The magnitudes of valence and conduction band edge splitting are measured by the two sp-d exchange constants $N_0\alpha$ and $N_0\beta$. The $N_0\alpha$ parameter determines the s-d exchange interaction between the s carriers of conduction bands and d-Cr levels, while the $N_0\beta$ describes the p-d exchange coupling between the p states of carriers of valence bands and d-Cr levels. We have used the mean field theory (Sanvito et al., 2001; Raebiger et al., 2004) to calculate the exchange constants of Ca_{1-x}Cr_xO compounds given by the following relations.

$$N_0 \alpha = \frac{\Delta E_c}{x \langle s \rangle} \tag{3}$$

$$N_0\beta = \frac{\Delta E_\nu}{x\langle s \rangle} \tag{4}$$

The $\Delta E_{\nu} = E_{\nu}^{\downarrow} - E_{\nu}^{\uparrow}$ and $\Delta E_{c} = E_{c}^{\downarrow} - E_{c}^{\uparrow}$ difference energies correspond, respectively, to the valence band-edge and

TABLE 5 | Computed conduction band-edge $\Delta E_c(eV)$ and valence band-edge $\Delta E_v(eV)$ spin-splittings, and sp-d exchange constants $N_0\alpha$ and $N_0\beta$ for Ca_{1-x}Cr_xO at concentrations x = 0.25, 0.5, and 0.75.

Material	$\Delta E_{\rm c}$ (eV)	$\Delta E_{\rm v}$ (eV)	Nοα	Νοβ
Ca _{0.75} Cr _{0.25} O	-0.858	-3.030	-1.716	-6.060
Ca _{0.5} Cr _{0.5} O	-0.741	-3.643	-0.741	-3.643
Ca _{0.25} Cr _{0.75} O	-0.972	-4.431	-0.648	-2.954

conduction band-edge spin-splittings at Γ high symmetry point. The $\langle s \rangle$ and x are the half total magnetic moment per Cr and the concentration of Cr, respectively (Sanvito et al., 2001). The calculated ΔE_{ν} , ΔE_c , $N_0 \alpha$, and $N_0 \beta$ are summarized in **Table 5**. Yaqoob et al. (2019) have predicted that the negative values of $N_0 \alpha$ and $N_0 \beta$ are due to the quantum confinement effect or structural symmetry changes that modify the coupling of different states. For Ca_{1-x}Cr_xO materials, the negative values of $N_0 \alpha$ and $N_0 \beta$ describe the anti-ferromagnetic coupling between the valence and conduction bands and the 3d states of magnetic Cr atoms.

CONCLUSIONS

We have characterized the structural properties, the spinpolarized electronic structures, and ferromagnetic performance induced by the Cr impurities in Ca1-xCrxO compounds at concentrations x = 0, 0.25, 0.5, and 0.75. The Ca_{1-x}Cr_xO doping materials are dynamically stable due to their positive phonon frequencies. The structural parameters and indirect gap of CaO are very significant with respect to the recent calculations found by GGA-WC and TB-mBJ. For Ca_{1-x}Cr_xO, the lattice constant decreases with increasing Cr concentration, leading to the increase in bulk modulus, where the sizes of the ionic radii of Ca and Cr atoms are the factors determining these changes. The Ca_{1-x}Cr_xO systems have a half-metallic ferromagnetic feature, where the ferromagnetism is favored by the large contribution of direct exchange splitting than that of the crystal field. The analysis of magnetic properties shows that both double-exchange and p-d exchange mechanisms participate to stabilize ferromagnetic state configuration. The half-metallic ferromagnets Ca_{1-x}Cr_xO compounds maintain a half-metal gap feature for all concentrations with spin polarization of 100%, making them suitable spin-injection candidates for possible exploration in semiconductors spintronics.

DATA AVAILABILITY STATEMENT

All datasets presented in this study are included in the article/supplementary material.

AUTHOR CONTRIBUTIONS

With the submission of this manuscript, all authors declare that the manuscript is original. All authors of this research

paper have contributed to this manuscript. All authors of this paper have read and approved the final version submitted. The contents of this manuscript have not

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Conflict of Interest: The authors declare that the research was conducted in the absence of any commercial or financial relationships that could be construed as a potential conflict of interest.

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